



PART SPECIFICATION

Description: CRGV - High Voltage Thick Film Chip Resistors

Tyco Electronics Family

CRGV 0603 1/16W +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGVP 0603 1/10W-S +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGV 0805 1/10W +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGV 0805 1/8W-S +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGV 1206 1/8W +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGVP 1206 1/4W-S +/- 1% & 5% 100KΩ ~ 10MΩ T/R CRGV 2010 1/2W +/- 1% & 5% 50KΩ ~ 10MΩ T/R CRGV 2512 1W +/- 1% & 5% 50KΩ ~ 10MΩ T/R CRGV 2512 1W +/- 1% & 5% 50KΩ ~ 10MΩ T/R

Appre	oved by	

Parts corresponding to RoHS Compliant: 2005-Apr.-1

Approved	Checked	Prepared
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Rev 2 2013/02/14



CRGV - High Voltage Thick Film Chip Resistors



1. Scope:

This specification for approval relates to High Voltage Thick Film Chip Resistors manufactured by Tyco Electronics specifications.

2. Type designation:

The type designation shall be in the following form:

Ex.

Type	Power Rating	Resistance tolerance	Nominal Resistanc	
CRGV 0603	1/16W			
CRGVP 0603	1/10W-S	8		
CRGV 0805	1/10W			
CRGVP 0805	1/8W-S	F - 1%	1K0	
CRGV 1206	1/8W	J - 5%		
CRGVP 1206	1/4W-S			
CRGV 2010	1/2W	I		
CRGV 2512	1W	1		

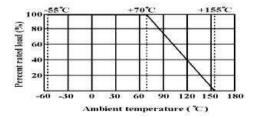
3. Ratings:

Type		CRGV0603	CRGV0805	CRGV1206	CRGV2010	CRGV2512				
no company	CRGV	0.0625W	0.10W	0.125W	0.50W	1W				
Power Rating	CRGVP	0.10W	0.125W	0.25W	9	2				
Maximum Work	ing Voltage	200 V	400 V	500 V	2000 V	3000 V				
Maximum Overl	oad Voltage	400 V	800 V	1000 V	3000 V	4000 V				
Dielectric Withst	tanding Voltag	300 V	500 V	500 V	500 V	500 V				
Temperature Rar	nge	-55°C +155°C								
Ambient Temper	ature		70°C							

3.1 Power rating:

Resistors shall have a power rating based on continuous load operation at an ambient temperature of 70°C. For temperature in excess of 70°C, the load shall be derated as shown in figure 1.

Figure 1



3.2 Voltage Rating:

Resistors shall have a rated direct-current (DC) continuous working voltage or an approximate sine-wave root-mean-square (RMS) alternating-current (AC) continuous working voltage at commercial-line frequent and waveform corresponding to the power rating, as determined from the following formula:

$$RCWV = \sqrt{P \times R}$$

Where: RCWV = Rated DC or RMS AC continuous working voltage at commercial-line frequency and waveform (volt)

P = Power Rating (watt)

R = Nominal Resistance (ohm)

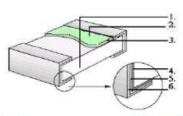
In no case shall the rated DC or RMS AC continuous working voltage be greater than the applicable maximum value.



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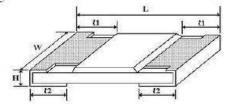


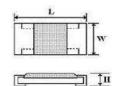
4. Construction:



- 1. High purity alumima substrate
- 2. Protective coating
- 3. Resistive element

- 4. Termination (Inner) Ni / Cr
- 5. Termination (Between) Ni barrier
- 6. Termination (Outer) Sn
- 5. Power rating and dimensions





Dimension:

		Dimension (mm)									
Туре	L	W	H	€1	€2						
0603	1.60 ± 0.10	0.80 + 0.15 - 0.10	0.45 ± 0.10	0.30 ± 0.20	0.30 ± 0.20						
0805	2.00 ± 0.15	1.25 + 0.15 - 0.10	0.55 ± 0.10	0.40 ± 0.20	0.40 ± 0.20						
1206	3.10 ± 0.15	1.55 + 0.15 - 0.10	0.55 ± 0.10	0.45 ± 0.20	0.45 ± 0.20						
2010	5.00 ± 0.10	2.50 + 0.15 - 0.10	0.55 ± 0.10	0.60 ± 0.25	0.50 ± 0.20						
2512	6.35 ± 0.10	3.20 + 0.15 - 0.10	0.55 ± 0.10	0.60 ± 0.25	0.50 ± 0.20						

Power Rating:

Туре	Power Rating at 70°C	Tolerance %	Resistance Range	Standard Series
0603	0.10W-S	± 1	$100 \text{K}\Omega \sim 10 \text{M}\Omega$	E-96
0003	0.0625W	± 5	100ΚΩ ~ 10ΜΩ	E-24
2005	0.125W-S	± 1	$100 \text{K}\Omega \sim 10 \text{M}\Omega$	E-96
0805	0.1W	± 5	$100 K\Omega \sim 10 M\Omega$	E-24
1206	0.25W-S	± 1	100ΚΩ ~ 10ΜΩ	E-96
1206	0.125W	± 5	100ΚΩ ~ 10ΜΩ	E-24
2010	0.5077	± 1	$50 \text{K}\Omega \sim 10 \text{M}\Omega$	E-96
2010	0.50W	± 5	$50K\Omega\sim10M\Omega$	E-24
2512		± 1	50ΚΩ ~ 10ΜΩ	E-96
2512	1W	± 5	$50K\Omega \sim 10M\Omega$	E-24



- TE

6. Marking: 6.1 Resistors A. ± 5% Tolerance 0603, 0805, 1206, 2010, 2512: the first two digits are significant figure of resistance and the third onedenoted number of zeros.

Ex. 333 33K

B. For ohmic values below 10 Ω Ex. 2R2 2.2 ohms

C. For E-96 series [±1% (F) tolerance] in 0603 size 3 digit system (due to space restrictions) please refer to page 8 for coding formula

Ex. 02C 10.2K

D. $\pm 1\%$ Tolerance 0805, 1206, 2010, 2512: 4 Digits, the first three digits are singnificant figures of resistance and the fourth digit denoted number of zeros

.Letter"R" is for decimal point.

Ex. 2701 2.7K

6.2 Labels

Label shall be marked with the following item:

Label shall be marked with the following item:

- A. Nominal Resistance and Resistance Tolerance
- B. Power Rating and Size
- C. Quantity
- D. Part No.
- E. P.O.No.
- F. Lot No.

tyco /	Electronic		NEOHM
RESISTANCE:	100K	Ω	± 5%
WATTAGE:	1/4W-S	SIZE:	CRGV1206
QUANTITY:	5,000	PCS	Pb-Free
PART NO.:	1879535-1	RoHS	2002/95/EC
LOT NO.:	1234567	REF #	1234567389



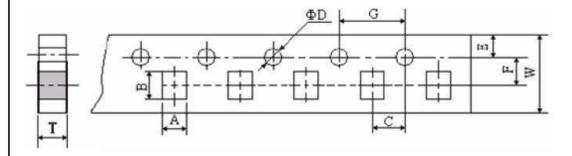
	High Voltage Thi	ck Film Ch	ip Resistors	= TE		
7. Performance	e specification :					
Characteristics	Limits		Test Meth	ods		
Characteristics	Limits		(JIS C 520	1-1)		
		4.8 Natural re	sistance change per t	temp.		
		degree centigi	rade.			
		R2-R1				
		84	x 106 (PPM/°	C)		
Temperature Coefficient	\pm 200 PPM/°C	R1(t2-t1)				
Cocinicien		R1: Resistance	e value at room temp	erature (t1)		
		R2: Resistanc	e value at room temp	o. plus 100 °C (t2)		
		Test pattern :	Room Temperature(t1),		
	(Room temper	ature +100°C (t2)			
Short time overload	Resistance change rate is	4.13 Permane	nt resistance change	after the application of a		
Short time overload	±(2.0%+0.1Ω) Maximum	potential of 2.	seconds			
	05 0/ agreement Minimum	Test temperature of solder : 245 ± 3°C				
	95 % coverage Minimum	Dipping time in solder : 2~3 seconds				
· ·		Reflow:	PEAK TALUE TEMPEKATI Z45°C - Z5			
		250	230°C			
Solderability	Go up tin rate bigger than half of	200	180°C	TIME		
	end pole.	150	150°C - 90±3	Os \		
	± 0.04 € 0.00 €	100	20	0±10s		
		50		TIME SOLDER TIME		
		4.19 Resistan	ce change after conti	nuous		
		MANAGE THE CONTRACTOR OF THE	uty cycle specified b			
	Resistance change rate is	Step	Temperature	Time		
Temperature	± 5% (1.0% + 0.05 Ω) Maximu	1	-55°C ± 3°C	30 mins		
cycling	± 1% (0.5% + 0.05 Ω) Maximu	2	Room temp.	10~15 mins		
		3	$+155^{\circ}\text{C} \pm 2^{\circ}\text{C}$	30 mins		
		4	Room temp.	10~15 mins		
Humidity	Resistance change rate is	4.24 Tempora	ry resistance change	after 1,000 hours		
(Steady State)	$\pm (3.0\% + 0.1\Omega)$ Maximum	exposure in a	humidity test chamb	er controlled at 40±2°C		
		and 90~95% 1	relative humidity			
	Resistance change rate is		(T)	hours (1.5 hours "on",		
Load life in Humidty	$\pm (3.0\% + 0.1\Omega)$ Maxium			midity chamber controlled		
	Resistance change rate is		and 90 to 95 % rela nent resistance chang			
Load Life	$\pm (3.0\% + 0.1\Omega)$ Max.		Will world the State and property the state of the state	urs"on", 0.5 hour"off" at		
3.857.21 (A.550.0 F.S. T.C. 1976-5).	1 ESS NEWS E 427 (1992 AND	$70^{\circ}\text{C} \pm 2^{\circ}\text{C}$ at				
Terminal Bending	Resistance change rate is	4.33 Twist of				
2 crimina Denoing	$\pm (1.0\% + 0.05\Omega)$ Max.	Y/X = 3/90 m	m for 60 seconds			



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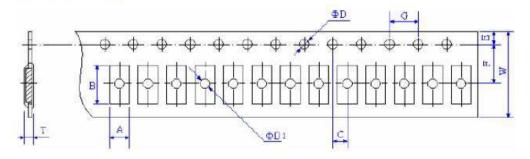


- 6. Packing specification:
- 6.1 Taping Dimension (mm)
- A. Paper taping



Type	A ± 0.2	B ± 0.2	C ± 0.05	φD+0.1	E ± 0.1	F ± 0.05	G ± 0.1	W ± 0.2	T ±0.1
0603	1.10	1.90	2.0	1.5	1.75	3.5	4.0	8.0	0.67
0805	1.65	2.40	2.0	1.5	1.75	3.5	4.0	8.0	0.81
1206	2.00	3.60	2.0	1.5	1.75	3.5	4.0	8.0	0.81
2010	2.80	5.40	2.0	1.5	1.75	5.5	4.0	12.0	0.75

B. Embossed taping



	Type	A ±0.2	B ±0.2	C ±0.05	φD+0.1 -0	E ±0.1	F ±0.05	G ±0.1	W ±0.2	φ D1+0.1 -0
16	2512	3.50	6.70	2.0	1.5	1.75	5.5	4.0	12.0	1.0



-TE High Voltage Thick Film Chip Resistors 7.2 Reel Dimension (mm) Quantity Per Reel $A \pm 0.5$ $B \pm 0.5$ $C \pm 0.5$ $D \pm 1$ $M \pm 2$ $W \pm 1$ Type Packaging 2 0603 Paper 5,000 pcs. 13 21 60 178 10 0805 Paper 5,000 pcs. 2 13 21 60 178 10 1206 Paper 5,000 pcs. 2 13 21 60 178 10 2010 4,000 pcs. 2 13 21 60 178 13.8 Paper 2512 Embossed 4,000 pcs. 2 13 60 178 13.8 21



High Voltage Thick Film Chip Resistors



Mutiplier Code:

Code	A	В	C	D	E	F	G	H	X	Y	Z
*	0	1	2	3	4	5	6	7	-1	-2	-3
Multiplier	10	10	10	10	10	10	10	10	10	10	10

Coding Formula

XX X

Example :

Multiplier Code

 $10.2\mathbf{K}\Omega = \begin{array}{cccc} 102 & \mathbf{X} & 10 & \Omega & = & 02\mathbf{C} \\ & \downarrow & & \downarrow & \\ 02 & & & \mathbf{C} \end{array}$

 $33.2 \Omega = 332 \quad \mathbf{X} \quad 10 \quad \Omega = 51 \mathbf{X}$

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E96 Marking Code Table

Resistance Code

Value	Code	Value	Code	Value	Code	Value	Code	Value	Code
100	01	162	21	261	41	422	61	681	81
102	02	165	22	267	42	432	62	698	82
105	03	169	23	274	43	442	63	715	83
107	04	174	24	280	44	453	64	732	84
110	05	178	25	287	45	464	65	750	85
113	06	182	26	294	46	475	66	768	86
115	07	187	27	301	47	487	67	787	87
118	08	191	28	309	48	499	68	806	88
121	09	196	29	316	49	511	69	825	89
124	10	200	30	324	50	523	70	845	90
127	11	205	31	332	51	536	71	866	91
130	12	210	32	340	52	549	72	887	92
133	13	215	33	348	53	562	73	909	93
137	14	221	34	357	54	576	74	931	94
140	15	226	35	365	55	590	75	953	95
143	16	232	36	374	56	604	76	976	96
147	17	237	37	383	57	619	77		
150	18	243	38	392	58	634	78		
154	19	249	39	402	59	649	79		
158	20	255	40	412	60	665	80		

^{*}Marking for 0603 E-96 series, the resistance value that no have multiplier code indicate marking follow this:

The first two digits are significant figures of resistance and the third one denoted number of zeros and under line the marking letters.

Ex.



1.2KΩ



